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PAPER	
CODE	0112-203B/RE-Backlog

F.Y. B. TECH. (SEMESTER - I)

COURSE CODE: ET10203B

(PATTERN 2020)

[Max. Marks: 60]

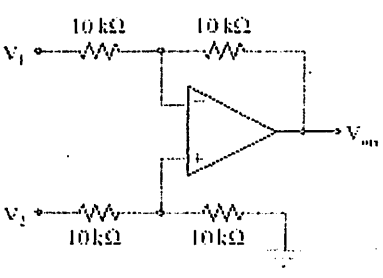
1) Figures to the right indicate full marks.

2) Use of scientific calculator is allowed

3) Use suitable data where ever required

Question No.	Question Description	Marks	CO mapped	Blooms Taxonomy Level
Q.1	i) For a Center Tapped FWR, if PIV of each diode is 12.5 V, then calculate the peak value of transformer secondary voltage. a. 5.9 V c. 13.2 V b. 11.8 V d. 13.9 V	[2]	CO1	Understand
	ii) Consider a practical diode is reverse biased with a 10V battery and a series resistor of 1K. Calculate the voltage across the diode. a. 0.6 V c. 10 V b. 9.4 V d. 0 V	[2]	CO1	Apply
	iii) Which process of the Electron-hole pair is responsible for emitting of light? a) Generation c) Recombination b) Movement d) Diffusion	[2]	CO1	Understand
	iv) Two LED's are connected in series along with limiting resistance. It is supplied with 15 V DC supply and drop across each LED is 1.5 V, the value of limiting resistance for 10 mA current is----- a) 400 Ω c) 900 Ω b) 750 Ω d) 1200Ω	[2]	CO1	Apply

	a) 0° c) 270°	b) 180° d) 360°			
	xiii) In transistor amplifier circuit, VCC applied as 14 V. For maximum amplification of input signal at its output, what will be the value of VCE required? a) 14 V c) 7 V	b) 0.7 V d) 1.4 V	[2]	CO2	Apply
	xiv) In a transistor, $I_C = 100 \text{ mA}$ and $I_E = 100.2 \text{ mA}$. The value of β is a) 50 c) 100	b) 500 d) 200	[2]	CO2	Apply
	xv) In RC phase shift oscillator producing output at $f = 500 \text{ Hz}$, $R = 7.5 \text{ Kohm}$ then $C = \text{----}$. a) 0.01 micro F b) 0.017 micro F c) 0.012 nF d) 0.001 micro F		[2]	CO2	Apply
Q2	Solve any three out of four questions.				
	a) Draw voltage divider biasing CS amplifier circuit and Explain the significance of coupling and bypass capacitors connected in the circuit.		[5]	CO3	Understand
	b) Explain Turning OFF process of SCR with circuit diagrams.		[5]	CO3	Understand
	c) Calculate VGS and VDS for the MOSFET with voltage divider bias circuit, given parameters are $R_1 = 100 \text{ K}\Omega$, $R_2 = 15 \text{ K}\Omega$, $R_D = 200 \Omega$, $V_{DD} = 24 \text{ V}$. Assume this particular MOSFET has minimum values of $I_{D(on)} = 200 \text{ mA}$ at $V_{GS} = 4 \text{ V}$ and $V_{GS(th)} = 2 \text{ V}$.		[5]	CO3	Apply
	d) Sketch the internal structure of n-channel Enhancement type MOSFET and explain its drain characteristics?		[5]	CO3	Understand
Q.3	Solve any three out of four questions				
	a) Illustrate the working of op-amp as a voltage regulator using suitable diagram		[5]	CO4	Understand
	b) Explain the following terms related to a differential amplifier with necessary diagrams i) Virtual ground ii) Slew Rate		[5]	CO4	Understand
	c) If $V_1 = 2\text{V}$ and $V_2 = 1.5\text{V}$, calculate the output voltage. Also calculate output for the values of $V_1 = -2\text{V}$ and $V_2 = 4\text{V}$.		[5]	CO4	Apply

				
	<p>d) Draw the circuit diagram and sketch the output waveforms of op-amp comparator</p>	[5]	CO4	Apply